

1.0 SCOPE

- 1.1** This specification covers the detail requirements for a MOSFET driver. This circuit is processed in accordance with MIL-STD-883 and is fully compliant to paragraph 1.2.1.

It is highly recommended that this data sheet be used as a baseline for new military or aerospace source control drawings.

For typical applications and operating characteristics, consult Maxim's data books.

1.2 Part Numbers

Device	Part Number
-1	ICL7667M(X)/883B

1.3 Package

(X)	Package	Description
JA	J-8	8-Pin Ceramic Dual-In-Line Package (CERDIP)

Note: See *Package Information* section for package drawing and dimensions.

1.4 Absolute Maximum Ratings

(TA = +25°C, unless otherwise noted.)

VDD to GND	18V
Input Voltage	(VDD + 0.3V) to (GND - 0.3V)
Power Dissipation (Tj = +150°C)	
up to +70°C (CERDIP)	640mW
derate above +70°C (CERDIP)	8.00mW/°C
Operating Temperature Range	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10 sec)	+300°C

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1.5 Thermal Resistance

$\Theta_{JC} = 55^{\circ}\text{C}/\text{W}$
 $\Theta_{JA} = 125^{\circ}\text{C}/\text{W}$

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2.0 REQUIREMENTS

2.1 Electrical performance characteristics are specified in Table 1 and apply over the full ambient operating temperature range, unless otherwise specified.

TABLE 1. ELECTRICAL PERFORMANCE CHARACTERISTICS (Note 1)

CHARACTERISTICS	SYMBOL	CONDITIONS	DEVICE TYPES	GROUP A SUB-GROUPS	LIMITS MIN MAX	UNITS	
Logic 1 Input Voltage	V _{IH}	V _{DD} = 4.5V to 17V	All	1, 2, 3	2.0	V	
Logic 0 Input Voltage	V _{IL}	V _{DD} = 4.5V to 17V	All	1, 2, 3	0.8	V	
Input Current	I _{IN}	V _{IN} = 0V to 15V	All	1, 2, 3	-1 1	μA	
Output Voltage High	V _{OH}	V _{DD} = 15V, no load	All	1, 2, 3	14.95	V	
Output Voltage Low	V _{OL}	V _{DD} = 15V, no load	All	1, 2, 3	0.05	V	
Output Resistance	ROUT	V _{IN} = V _{IL} , I _{OUT} = 10mA	All	1	10	Ω	
				2, 3	15		
		V _{IN} = V _{IH} , I _{OUT} = -10mA		1	12		
				2, 3	20		
Power-Supply Current	I _{DD}	V _{IN} = 0V, both inputs	All	1, 2, 3	0.4	mA	
		V _{IN} = 3V, both inputs		1	7		
				2, 3	8		
Delay Time	t _{D1}	Figure 1	All	9	30	ns	
				10, 11	40		
	t _{D2}			9	50		
				10, 11	60		
Rise Time	t _R	Figure 1	All	9	30	ns	
				10, 11	40		
Fall Time	t _F	Figure 1	All	9	30	ns	
				10, 11	40		

Note 1: V_{DD} = +15V, unless otherwise noted.

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3.0 QUALITY ASSURANCE

- 3.1** Sampling and inspection procedures shall be in accordance with MIL-M-38510 and, to the extent specified, with MIL-STD-883.
- 3.2** Screening shall be in accordance with Method 5004 of MIL-STD-883.
 Burn-in test (Method 1015):
 - (1) Test condition A, B, C, or D.
 - (2) $T_A = +125^\circ\text{C}$, minimum.
 - (3) Interim and final electrical test requirements shall be as specified in Table 2.
- 3.3** Quality conformance inspection shall be in accordance with Method 5005 of MIL-STD-883 including groups A, B, C, and D inspection.
 Group A inspection:
 - (1) Tests as specified in Table 2.
 - (2) Selected subgroups in Table 1, Method 5005 of MIL-STD-883 shall be omitted.
- 3.4** Groups C and D Inspections:
 - a. End-point electrical parameters shall be as specified in Table 1.
 - b. Steady-state life test (Method 1005 of MIL-STD-883):
 - (1) Test condition A, B, C, or D.
 - (2) $T_A = +125^\circ\text{C}$, minimum.
 - (3) Test duration, 1000 hours, except as permitted by Method 1005 of MIL-STD-883.

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TABLE 2. ELECTRICAL TEST REQUIREMENTS

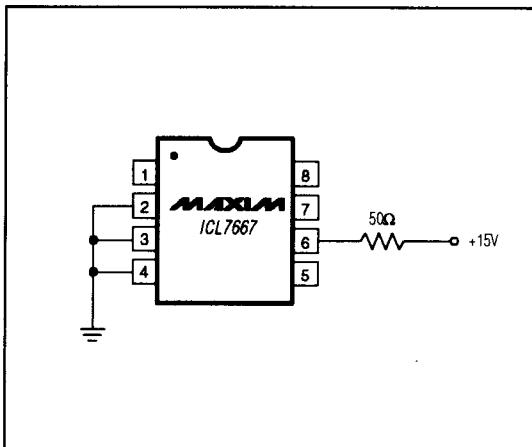
MIL-STD-883 Test Requirements	Subgroups (per Method 5005, Table 2)
Interim Electrical Parameters (Method 5004)	1
Final Electrical Parameters (Method 5004)	1, * 2, 3, 9
Group A Test Requirements (Method 5005)	1, 2, 3, 9, 10, ** 11**
Groups C and D End-Point Electrical Parameters (Method 5005)	1

* PDA applies to Subgroup 1 only.

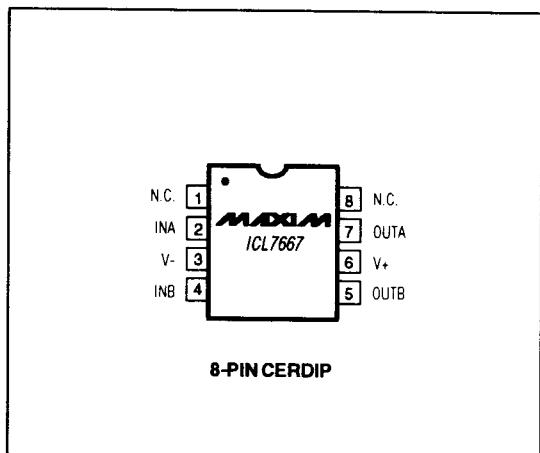
** Subgroups 10 and 11, if not tested, shall be guaranteed to the limits in Table 1.

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4.0 Life Test Burn-In Circuit



4.1 Pin Configuration



4.2 Timing Diagram/Test Circuit

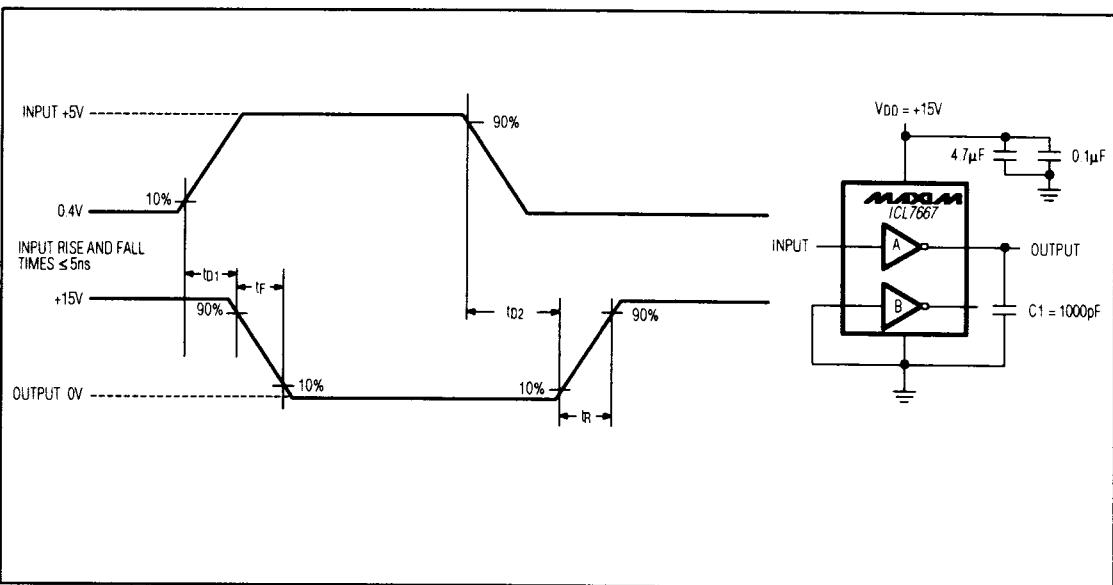


Figure 1.

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